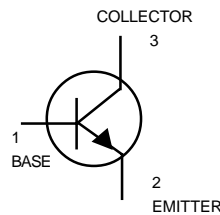


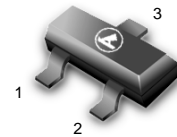
# General Purpose Transistors

## NPN Silicon

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**L2SC4617\*T1**



SC-89

● **Absolute maximum ratings** (Ta=25°C)

| Parameter                   | Symbol           | Limits   | Unit |
|-----------------------------|------------------|----------|------|
| Collector-base voltage      | V <sub>CBO</sub> | 60       | V    |
| Collector-emitter voltage   | V <sub>CEO</sub> | 50       | V    |
| Emitter-base voltage        | V <sub>EBO</sub> | 7        | V    |
| Collector current           | I <sub>c</sub>   | 0.15     | A    |
| Collector power dissipation | P <sub>c</sub>   | 0.15     | W    |
| Junction temperature        | T <sub>j</sub>   | 150      | °C   |
| Storage temperature         | T <sub>stg</sub> | -55~+150 | °C   |

● **Electrical characteristics** (Ta=25°C)

| Parameter                            | Symbol               | Min. | Typ. | Max. | Unit | Conditions   |
|--------------------------------------|----------------------|------|------|------|------|--|
| Collector-base breakdown voltage     | BV <sub>CBO</sub>    | 60   | -    | -    | V    | I <sub>c</sub> =50μA                               |
| Collector-emitter breakdown voltage  | BV <sub>CEO</sub>    | 50   | -    | -    | V    | I <sub>c</sub> =1μA                                |
| Emitter-base breakdown voltage       | BV <sub>EBO</sub>    | 7    | -    | -    | V    | I <sub>E</sub> =50μA                               |
| Collector cutoff current             | I <sub>cBO</sub>     | -    | -    | 0.1  | μA   | V <sub>CB</sub> =60V                               |
| Emitter cutoff current               | I <sub>EBO</sub>     | -    | -    | 0.1  | μA   | V <sub>EB</sub> =7V                                |
| Collector-emitter saturation voltage | V <sub>CE(sat)</sub> | -    | -    | 0.5  | V    | I <sub>c</sub> /I <sub>B</sub> =50mA/5mA           |
| DC current transfer ratio            | h <sub>FE</sub>      | 120  | -    | 560  | -    | V <sub>CE</sub> =6V, I <sub>c</sub> =1mA           |
| Transition frequency                 | f <sub>T</sub>       | -    | 180  | -    | MHz  | V <sub>CE</sub> =12V, I <sub>E</sub> =2mA, f=30MHz |
| Output capacitance                   | C <sub>ob</sub>      | -    | 2.0  | 3.5  | pF   | V <sub>CB</sub> =12V, I <sub>E</sub> =0A, f=1MHz   |

● **Device marking**

L2SC4617QT1=BQ L2SC4617RT1=BR L2SC4617ST1=BS

● h<sub>FE</sub> values are classified as follows:

| Item            | Q       | R       | S       |
|-----------------|---------|---------|---------|
| h <sub>FE</sub> | 120~270 | 180~390 | 270~560 |

● Electrical characteristic curves

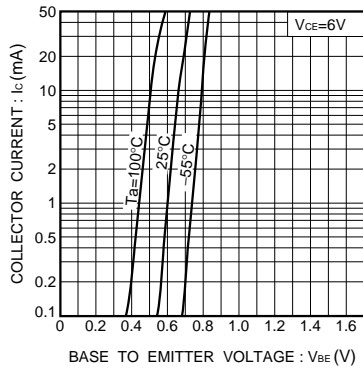


Fig.1 Grounded emitter propagation characteristics

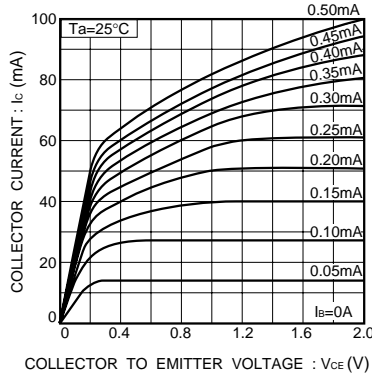


Fig.2 Grounded emitter output characteristics ( I )

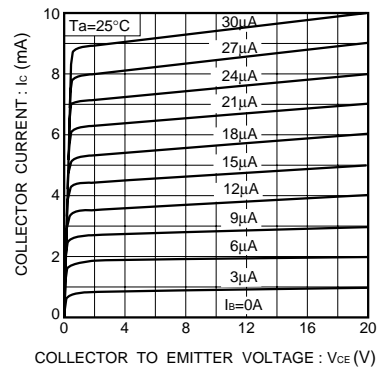


Fig.3 Grounded emitter output characteristics ( II )

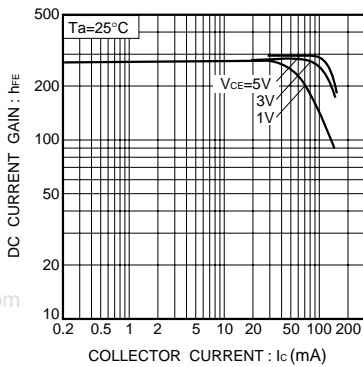


Fig.4 DC current gain vs. collector current ( I )

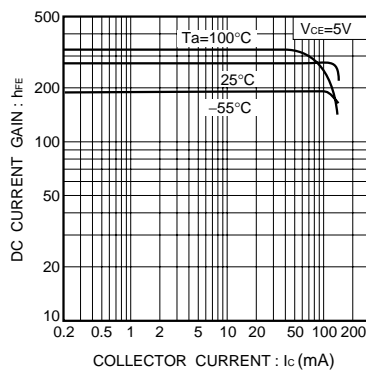


Fig.5 DC current gain vs. collector current ( II )

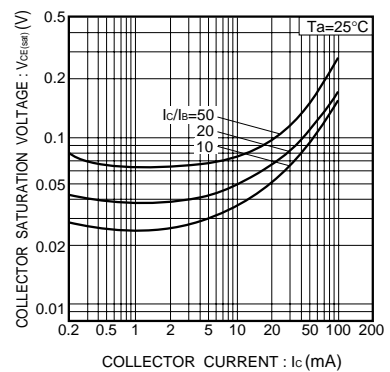


Fig.6 Collector-emitter saturation voltage vs. collector current

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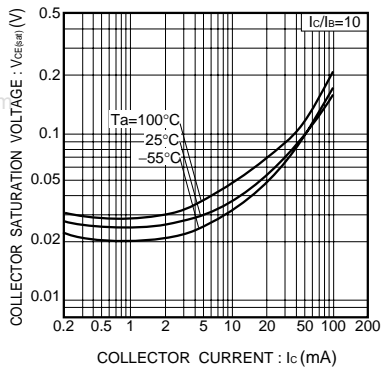


Fig.7 Collector-emitter saturation voltage vs. collector current ( I )

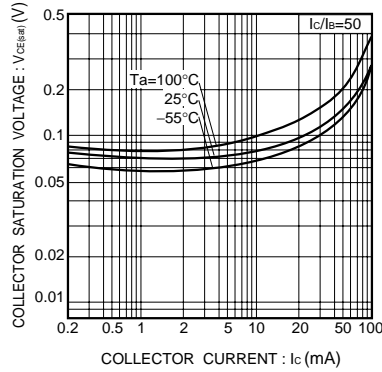


Fig.8 Collector-emitter saturation voltage vs. collector current (II)

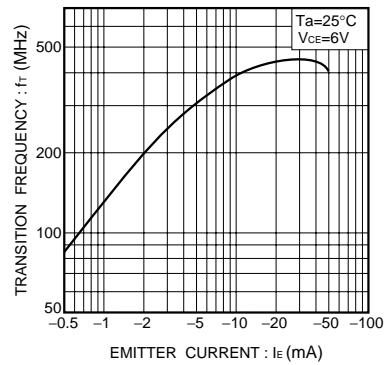


Fig.9 Gain bandwidth product vs. emitter current

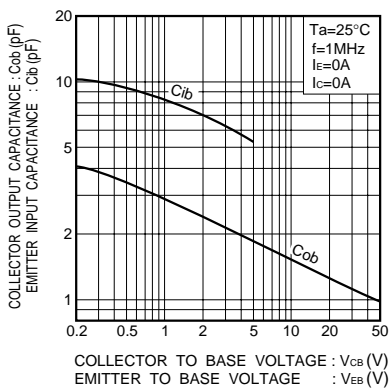


Fig.10 Collector output capacitance vs. collector-base voltage  
Emitter input capacitance vs. emitter-base voltage

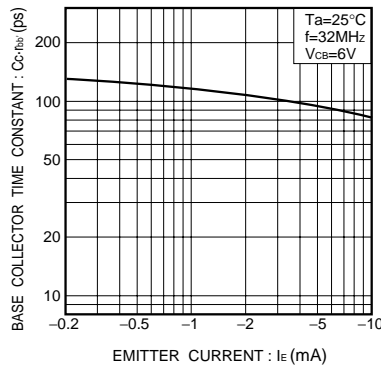
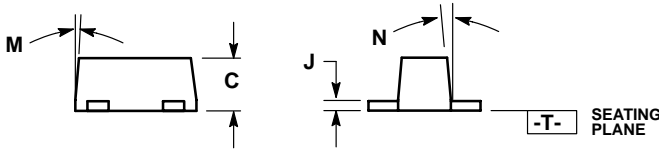
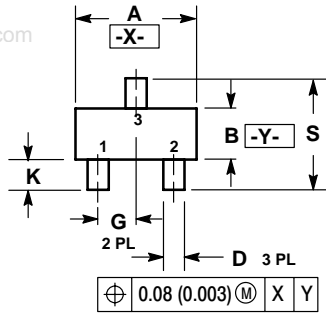


Fig.11 Base-collector time constant vs. emitter current

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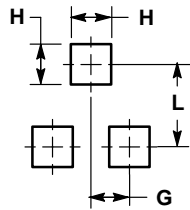
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NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 463C-01 OBSOLETE, NEW STANDARD 463C-02.

| DIM | MILLIMETERS |      |      | INCHES    |       |       |
|-----|-------------|------|------|-----------|-------|-------|
|     | MIN         | NOM  | MAX  | MIN       | NOM   | MAX   |
| A   | 1.50        | 1.60 | 1.70 | 0.059     | 0.063 | 0.067 |
| B   | 0.75        | 0.85 | 0.95 | 0.030     | 0.034 | 0.040 |
| C   | 0.60        | 0.70 | 0.80 | 0.024     | 0.028 | 0.031 |
| D   | 0.23        | 0.28 | 0.33 | 0.009     | 0.011 | 0.013 |
| G   | 0.50 BSC    |      |      | 0.020 BSC |       |       |
| H   | 0.53 REF    |      |      | 0.021 REF |       |       |
| J   | 0.10        | 0.15 | 0.20 | 0.004     | 0.006 | 0.008 |
| K   | 0.30        | 0.40 | 0.50 | 0.012     | 0.016 | 0.020 |
| L   | 1.10 REF    |      |      | 0.043 REF |       |       |
| M   | ---         | ---  | 10 ° | ---       | ---   | 10 °  |
| N   | ---         | ---  | 10 ° | ---       | ---   | 10 °  |
| S   | 1.50        | 1.60 | 1.70 | 0.059     | 0.063 | 0.067 |



RECOMMENDED PATTERN OF SOLDER PADS